

## T495D476K025ATE150

T495, Tantalum, MnO2 Tantalum, Commercial Grade, 47 uF, 10%, 25 VDC, SMD, MnO2, Molded, Low ESR, 150 mOhms, 7343, 3.1 mm, 1.3 mm

T495

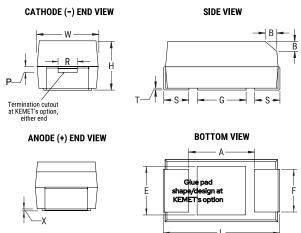
MnO2 Tantalum

SMD, MnO2, Molded, Low ESR

SMD Chip



Dimensions



-		L –	_
Click here for the 3D mov	اما		

BOTTOM VIEW  Glue pad E shape/design at KEMETs option	Features	Low ESR			
		RoHS	Yes		
		Termination	Tin		
		AEC-Q200	No		
	E shape/design at F	Typical Component Weight	446.84 mg		
		Shelf Life	156 Weeks		
	L	MSL	1		
ick here for the 3D model.					
		Specifications			
	7.3mm +/-0.3mm	Capacitance	47 uF		
	4.3mm +/-0.3mm	Tolerance	10%		
	2.8mm +/-0.3mm	Voltage DC	25 VDC (85C), 16.75 VDC (125C)		
	0.13mm REF	Temperature Range	-55/+125°C		

**General Information** 

Series Dielectric

Style

Description

L	7.3mm +/-0.3mm
W	4.3mm +/-0.3mm
Н	2.8mm +/-0.3mm
Т	0.13mm REF
S	1.3mm +/-0.3mm
F	2.4mm +/-0.1mm
Α	3.6mm MIN
В	0.5mm +/-0.15mm
E	3.5mm REF
G	3.5mm REF
Р	0.9mm REF
R	1mm REF
Χ	0.1mm +/-0.1mm REF

Packaging Specifications		
Packaging	T&R, 178mm	
Packaging Quantity	500	

Specifications	
Capacitance	47 uF
Tolerance	10%
Voltage DC	25 VDC (85C), 16.75 VDC (125C)
Temperature Range	-55/+125°C
Rated Temperature	85°C
Dissipation Factor	6% 120Hz 25C
Failure Rate	N/A
ESR	150 mOhms (100kHz 25C)
Ripple Current	1000 mA (rms, 100kHz 25C), 900 mA (rms, 85C), 400 mA (rms, 125C)
Leakage Current	11.8 uA (5min 25°C)

Statements of suitability for certain applications are based on our knowledge of typical operating conditions for such applications, but are not intended to constitute - and we specifically disclaim - any warranty concerning suitability for a specific customer application or use. This Information is intended for use only by customers who have the requisite experience and capability to determine the correct products for their application. Any technical advice inferred from this Information or otherwise provided by us with reference to the use of our products is given gratis, and we assume no obligation or liability for the advice given or results obtained.

Generated 09/01/2025 © 2006 - 2025 YAGEO

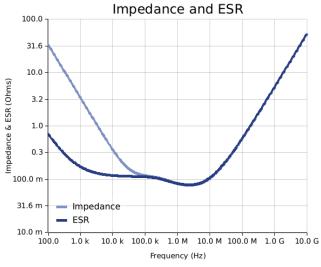


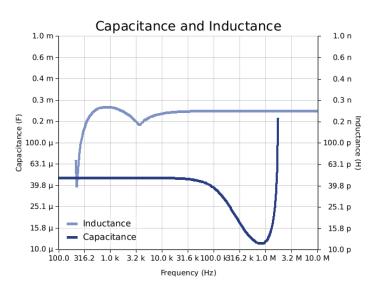


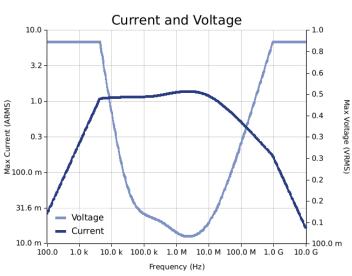
T495, Tantalum, MnO2 Tantalum, Commercial Grade, 47 uF, 10%, 25 VDC, SMD, MnO2, Molded, Low ESR, 150 mOhms, 7343, 3.1 mm, 1.3 mm

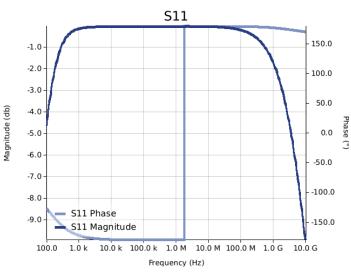
## **Simulations**

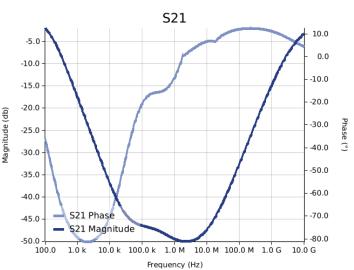
For the complete simulation environment please visit Y-SIM.











Generated 09/01/2025 © 2006 - 2025 YAGEO



## T495D476K025ATE150

T495, Tantalum, MnO2 Tantalum, Commercial Grade, 47 uF, 10%, 25 VDC, SMD, MnO2, Molded, Low ESR, 150 mOhms, 7343, 3.1 mm, 1.3 mm

## These are simulations.

This is not a specification!

The responses shown represent the typical response for each part type. Specific responses may vary, depending on manufacturing variation affects of all parameters involved, including the specified tolerances applied to capacitance and unspecified variations of ESR, ESL, and leakage resistance.

The responses shown do not represent a specified or implied maximum capability of the device for all applications.

- The ESR used for ripple "Ripple Current/Voltage vs. Frequency" plots is the ESR at ambient temperature.

- The ESR in the "Temperature Rise vs. Ripple Current" plots is the ESR at ambient temperature. The ESR in the "Temperature Rise vs. Ripple Current" plots is adjusted to each incremental temperature rise before the power and ripple current is calculated. The effects shown herein are based on measured data from a multiple part sample of the parts in question. Ripple capability of this device will be factored by thermal resistance (Rth) created by circuit traces (addi affects of all parameters involved, including the specified tolerances applied to capacitance and unspecified variations of ESR, ESL, and leakage resistance.

  The peak voltages generated in the "Temperature Rise vs. Combined Ripple Currents" plot are calculated for each frequency and are not combined with voltages
- generated at any other harmonics.

   Please consult with the catalog or field applications engineer for maximum capability of the device in specific applications.

All product information and data (collectively, the "Information") are subject to change without notice.

KEMET K-SIM is designed to simulate behavior of components with respect to frequency, ambient temperature, and DC bias levels. The responses shown represent the typical response for each part type. Specific responses may vary, depending on manufacturing variation effects of all parameters involved, including the specified tolerances applied to capacitance and unspecified variations of ESR, ESL, and leakage resistance.

All Information given herein is believed to be accurate and reliable, but is presented without guarantee, warranty, or responsibility of any kind, expressed or implied. Statements of suitability for certain applications are based on our knowledge of typical operating conditions for such applications, but are not intended to constitute – and we specifically disclaim – any warranty concerning suitability for a specific customer application or use. This Information is intended for use only by customers who have the requisite experience and capability to determine the correct products for their application. Any technical advice inferred from this Information or otherwise provided by us with reference to the use of our products is given gratis, and we assume no obligation or liability for the advice given or results obtained.

If you have any questions please contact K-SIM.

Generated 09/01/2025 © 2006 - 2025 YAGEO